Green-Red sensitive Solid State Photomultiplier with 1mm² active area



SSPM-050701GR-TO18 is a 1mm2 active area solid state photomultiplier with a broad and flat spectral response in the Green-Red domain (550-750nm). It has low noise characteristics, high gain and is suitable for a wide range of applications.

At room temperature this device has the best quantum efficiency available today for this technology. When modestly cooled, this device exhibits truly exceptional performance.



mechanical dimensions



notes

- All performance figures are indicative.
- Photonique can provide detailed characterization for individual SSPM's
- Diagrams and instructions for signal amplifier and biasing circuits are provided with SSPMs.
- CAUTION: For optimal integration and coupling to light sources, the light sensitive sensor is not enclosed - DO NOT SCRATCH OR OTHERWISE DAMAGE ITS SURFACE.
- ALL DATA SUBJECT TO CHANGE WITHOUT NOTICE

advantages

SSPM-050701GR-T018 is a superior solution for lowlight sensing applications between 450 and 800nm. It has low noise and an excess noise factor close to 1.15

At $T=-28C^{\circ}$, SSPM-050701GR-TO18 has a single photon detection efficiency (PDE) in excess of 40% over a wide spectral range while it achieves an outstanding 30% PDE at room temperature.

This performance is illustrated in the following graph where the separation between events containing 1 through 15 incident photons is clearly visible:



For further information please contact:

Photonique SA C.P. 1562 1211 Geneva-1 Switzerland

Web: www.photonique.ch Email: info@photonique.ch

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data sheet

SSPM-050701GR-T018

typical performance at $T = +22C^{\circ}$

| Parameter | Units | Typical Value | Comments |
|------------------------------------|-------|---------------------|---------------------------------------|
| Peak Sensitivity Wavelength | nm | 600 | $= \lambda_P$ |
| Single photon detection efficiency | % | 30 | at λ_P |
| Operating Voltage | V | 40 | $= V_R$ |
| Gain | | 0.8x10 ⁶ | at V_R |
| Dark current | μΑ | 2 | typical at V_R |
| Capacitance | pF | 35 | at V_R and readout rate f_R =1MHz |
| Excess noise factor | | 1.15 | at V_R , f_R and λ_P |
| Signal rise time | ns | <2 | |
| Operating Temperature | Co | 22 | -40 +40 |
| Storage Temperature | Co | | -40 +60 |

performance graphs





